

Gigabit Ethernet 1.25Gbps CWDM Transceiver TV8#xxx



- 1470 ~ 1610nm CWDM Transceiver with 20nm spacing
- 1.25Gbps Gigabit Ethernet (1000Base-LX)
- Single +3.3V or +5V Power Supply
- 1X9 Duplex SC Connector

Family Model – x : 3.3V or 5V

TV8Ax40/80

TV8Bx40/80

TV8Cx40/80

TV8Dx40/80

TV8Ex40/80

TV8Fx40/80

TV8Gx40/80

TV8Hx40/80

Features

- Compliant with IEEE 802.3z 1000BASE-LX specifications for Gigabit Ethernet
- Industry standard 1X9 package with duplex SC connector
- 1.47 μ m ~ 1.61 μ m uncooled InGaAsP SMQW distributed feed-back(DFB) LD with 20nm spacing
- High sensitive InGaAs PIN photodiode used at wavelengths from 1.1 μ m to 1.62 μ m
- Single +3.3V or +5V power supply
- LVPECL differential data inputs and outputs
- Operating temperature ; 0 to +70 $^{\circ}$ C/-40 to +85 $^{\circ}$ C
- Tested by Teradian's Reliability and Qualification Program
- Wavelength options(8 channels with 20nm spacing)
1470nm/1490nm/1510nm/1530nm/1550nm/1570nm/1590nm/1610nm
- Distance options
40km/80km with 9/125 μ m SMF

Description

The TV8#xxx series CWDM transceivers are designed to meet the Gigabit Ethernet LX specifications. The transceivers are manufactured in 1x9 pin package with duplex SC connector interface and made of plastic or metallized housing to obtain excellent EMI shielding..

The transmitter consists of a long wavelength(1.47 μ m ~ 1.61 μ m) InGaAsP SMQW DFB-LD in an optical subassembly(OSA) with 20nm wavelength intervals for 8 channel CWDM applications.

The OSA is driven by a custom IC which converts differential PECL logic signals into a laser

diode drive current. The receiver includes a planar InGaAs PIN photodiode mounted with a transimpedance preamplifier IC in an OSA. The OSA is mated to a custom limiting-amplifier which provides post-amplification and signal detect function(active high).

The transceivers are designed to used in a single power supply(+3.3V or +5V) and an operating temperature range of 0°C to +70°C or -40°C to +85°C.

Applications

The transceiver operates at 1.25Gbps for Gigabit Ethernet on multimode or single mode fiber.

- CWDM applications
- Gibabit Ethernet / LAN switch
- High-speed data links
- Metropolitan Area Network

Absolute Maximum Ratings

Parameters	Symbol	Unit	Min.	Max.	Remarks
Ambient Operating Temperature	T _{op}	°C	0	70	Indoor use
			-40	85	Outdoor use
Storage Temperature	T _{stg}	°C	-40	85	
Supply Voltage	V _{CC} -V _{EE}	V	-0.5	6.0	
Lead Soldering Temperature/Time		°C/sec		260/10	
Relative Humidity	RH	%	-	95	

Electrical Characteristics

Parameters		Symbol	Unit	Min.	Typ.	Max.	Remarks
DC Power Supply Voltage		V _{CC} -V _{EE}	V	3.1 4.75	3.3 5	3.5 5.25	3.3V 5V
DC Power Supply Current		I _{CC,TX} I _{CC,RX}	mA mA	60 95		140 150	5V option
Input Data Voltage	Low	V _{IL} - V _{CC}	V	-1.810 -1.165		-1.475 -0.880	3.3V/5V
	High	V _{IH} - V _{CC}					
Output Data Voltage	Low	V _{OL} - V _{CC}	V	-1.892 -1.051		-1.548 -0.879	3.3V/5V
	High	V _{OH} - V _{CC}					
Output SD Voltage	TTL	Low	V _{SD, Low}	-		0.8	3.3V
		High	V _{SD, High}	2.2		-	
	option	Low	V _{SD, Low}	-		0.8	5V
		High	V _{SD, High}	4.2		-	

Eye Diagram

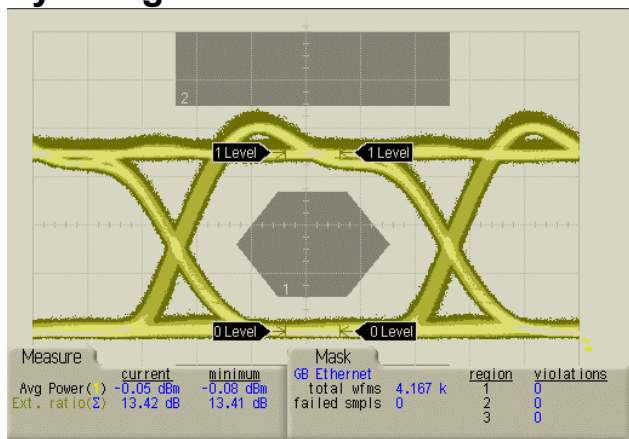


Fig. 1 Back-to-back TV85580, PRBS 2²³ - 1 with 2.5Gbps filter

Optical Characteristics

(T_{op} = 25°C)

Parameters	Symbol	Condition	Unit	Min.	Typ.	Max.	Remark
Data Bit Rate		PRBS 2 ⁷ -1,NRZ	Gbps		1.25		
Fiber Length 9µm core SMF		1x10 ⁻¹² BER, 1.25Gbps	Km			80	
TRANSMITTER							
Average Power Output	P _{OUT}	I _f =I _{BIAS} + I _{mod} /2	dBm	-4 -1.0	-3.0 0	-1.0 +2.0	40km 80km
Extinction Ratio	ER		dB	9			
Center Wavelength	λ _c	CW, @ P _{OUT}	nm	1468 1488 1508 1528 1548 1568 1588 1608	1470 1490 1510 1530 1550 1570 1590 1610	1472 1492 1512 1532 1552 1572 1592 1612	TV8AXXX TV8BXXX TV8CXXX TV8DXXX TV8EXXX TV8FXXX TV8GXXX TV8HXXX
Spectral Width	Δλ	RMS Width Max. -20dB WD	nm			1.0	
Side Mode Suppression Ratio	SMSR		dB	30			
Optical Rise/Fall Time	t _r /t _f	20 - 80%	nsec			0.26	
Relative Intensity Noise	RIN		dB /Hz			-120	
Total Transmitter Jitter Added at TP2			psec			227	

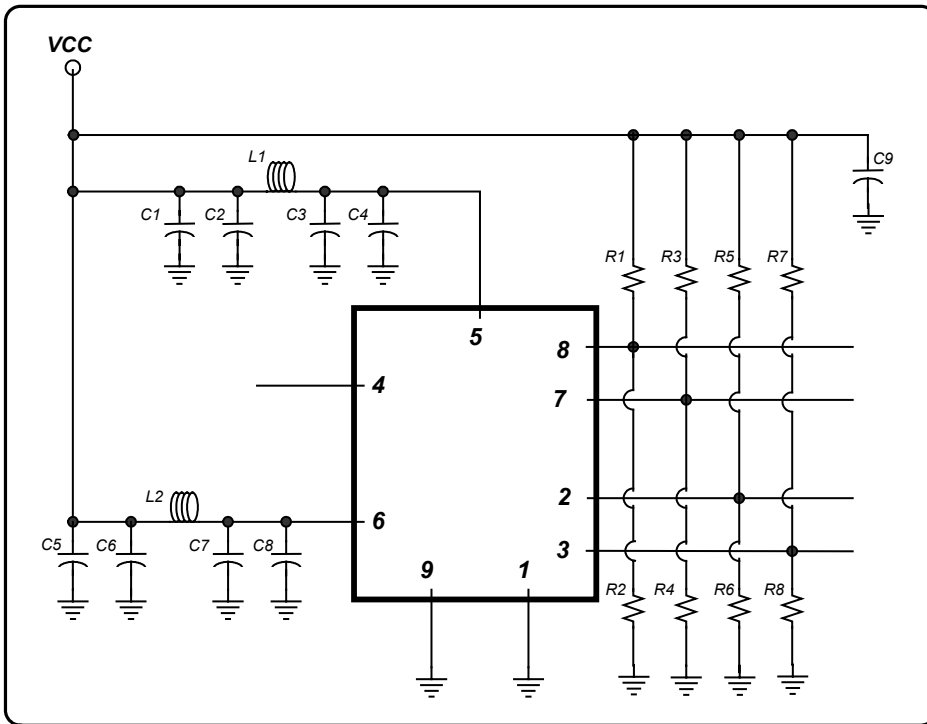
RECEIVER							
Sensitivity (Average Input Power)	$P_{IN,MIN}$	PRBS 2^7-1 , 10^{-12} BER	dBm		-22	-21 -25	40km 80km
Receiver Overload	$P_{IN,MAX}$		dBm	-3.0			
Electrical 3dB Upper Cutoff Frequency			MHz			1500	
Signal Detect Threshold Decreasing light input	P_D		dBm	-30			
Increasing light input	P_A		dBm			-20	
Signal Detect Hysteresis	$P_A - P_D$		dB	0.5	1.0		

Pin Descriptions

Pin No.	Symbol	Description	Level/Logic
1	V_{EER}	Rx Ground	Power supply
2	RD+	Rx Data out(+)	PECL
3	RD-	Rx Data out(-)	PECL
4	SD	RX Signal detect. (Logic HIGH for normal operation)	TTL output
5	V_{CCR}	Rx Power supply	Power supply
6	V_{CCT}	Tx Power supply	Power supply
7	TD-	Tx Data in(-)	PECL
8	TD+	Tx Data in(+)	PECL
9	V_{EET}	Tx Ground	Power supply

Recommended Interface Circuit

The transceiver can operate with PECL logic level. The interface circuit with direct-coupled PECL interface is shown in Figure 1. When interfacing with non-PECL logic level, AC coupling can be used as shown in Figure 2. The Signal Detect circuit monitors the incoming optical signal and generates a logic LOW signal when the optical signal is lower than a predefined level. The power supply filters are required for good EMI performance and should be as close to the transceiver as possible.

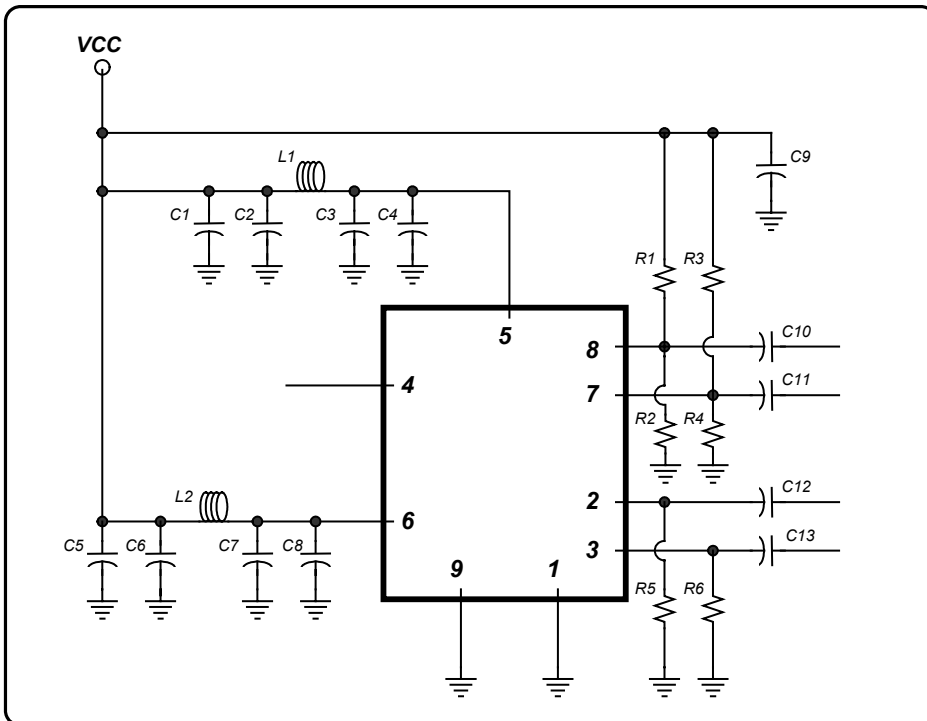


$C1=C4=C5=C8=10\mu\text{F}$,
 $C2=C3=C6=C7=0.1\mu\text{F}$,
 $C9=0.1\mu\text{F}$,

$L1=L2=1.0\mu\text{H}$ or
 Ferrite inductor

$R1=R3=R5=R7=82\Omega$
 (5.0V) or 82Ω (3.3V),
 $R2=R4=R6=R8=130\Omega$
 (5.0V) or 130Ω (3.3V),

Fig. 2 DC-Coupled PECL Interface



$C1=C4=C5=C8=10\mu\text{F}$,
 $C2=C3=C6=C7=0.1\mu\text{F}$,
 $C9=0.1\mu\text{F}$, $R1=R3=68\Omega$
 (5.0V) or 82Ω (3.3V),

$R2=R4=180\Omega$ (5.0V)
 130Ω (3.3V),
 $R5=R6=270\Omega$ (5.0V)
 or 142Ω (3.3V),

$C10=C11=C12=C13=0$
 $.1\mu\text{F}$,

$L1=L2=1.0\mu\text{H}$
 or Ferrite inductor

Figure 3. AC-Coupled PECL Interface.

Outline Diagram

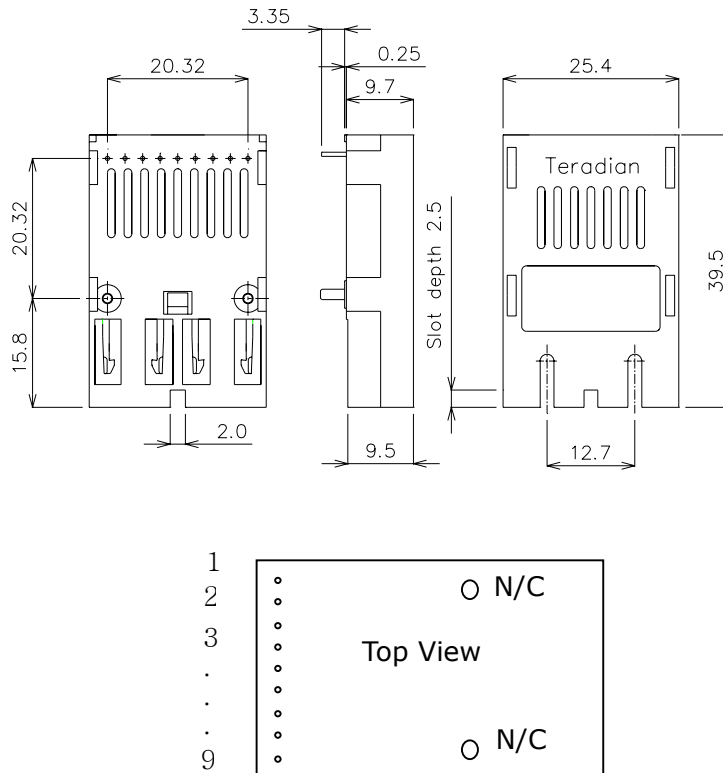


Fig.4 SC duplex Transceiver Package Dimensions [unit: mm]

! Handling Caution

The transceiver can be damaged by overvoltage and current surges. Precautions should be taken for transient power supply.

This device is susceptible to damage as a result of electrostatic discharge(ESD). Take proper precautions during both handling and testing

! Caution

- All adjustments are made at the factory before shipment to our customers. No maintenance and alteration to device is required.
- Tampering with or modifying the performance of the modules will result in voided product warranty. It may also result in improper operation of the circuitry, and possible overstress of the semiconductor components. Device degradation or product failure may result.
- Use of controls or adjustments or procedures other than those specified herein (ex : Connection of the modules to a non-approved optical source, operating above the recommended absolute maximum conditions, operating in a manner inconsistent with unit design and function) may result in hazardous radiation exposure and may be considered an act of modifying or manufacturing a laser product. The person(s) performing such an act is required by law to recertify the laser product under the provisions of US 21CFR (Subchapter J).
- The use of optical instruments with this product will increase eye hazard.

Notice
On operation, If optical connectors are unterminated, modules can emit invisible laser radiation. Avoided eye exposure to direct or indirect radiation

Ordering Information

Com pany	Func- tion	Data Rate	Wavelength	Supply Voltage	Distance	Pin	Temp. Range	Shielding
T	V	8	C	3	40	9	I	N
Tera dian	V ;TRV S ;SFF F ;SFP B ;Bi-Di TRV. (Recep- tacle) D ;Bi-Di TRV. (Pig- tailed)	1 ;155Mbps 4 ;622Mbps F ;1.06Gbps 8 ;1.25Gbps S ;2.12Gbps G ;2.5Gbps A ;Asy. Bi-Di 622M/155M E ;Asy. Bi-Di 1.25G/155M O ;Order- made	3 ;1.3μm 5 ;1.55μm 6 ;Bi-Di T1.3/R1.5 7 ;Bi-Di T1.5/R1.3 8 ;850nm A ;1470nm B ;1490nm C ;1510nm D ;1530nm E ;1550nm F ;1570nm G ;1590nm H ;1610nm M ;1270nm N ;1290nm O ;1310nm P ;1330nm Q ;1350nm R ;1370nm S ;1390nm T ;1410nm U ;1430nm W ;1450nm	3 ;3.3V 5 ;5V	SX ;Note1 02 ;2km LX ;5km 10 ;10km 15 ;15km 20 ;20km 30 ;30km 40 ;40km 60 ;60km 80 ;80km A0 ;100km C0 ;120km	1 ;2X5 (10 pin) 2 ;2X10 (20 pin) 9 ;1X9 (9 pin)	I ;Indoor Use (0~70℃) O ;Outdoor Use (-40~85℃)	N ;No Shield M ;Metal coating

*Note 1 ;
 - 220m with 62.5/125μm MMF @1.25Gbps
 - 500m with 50/125μm MMF @1.25Gbps
 - 200m with 62.5/125μm MMF @2.125Gbps

*Note 2 ; additional order information
 - Connector type default is SC/PC and the default length of fiber is 1m
 - In case of ordering pigtailed Bi-Di Transceiver, please specify specs. clearly if not default.

More Information

Teradian Inc.

Address 946, Dunsan-dong, Seo-gu, Daejeon, 302-120, Korea
Tel +82-42-476-4800, 4803(Oversea Sales Team)
Fax +82-42-476-4805
Homepage <http://www.teradian.com>
e-mail sales@teradian.com